GMSI WS Carbon Nanotube Growth, Separation and Spectroscopy@ Tokyo, October 5, 2012

Nitrogen Incorporated Vertically Aligned SWNTs

(7,7)





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50 um

Carbon Nanotube and Nano-Therm. Lab.



Professor: 1(0); Associate Professor: 1(0); Lecturer: 1(1); Assistant Professor: 1(0); Technician: 1(0); Secretary: 2(0), PD: 4(3); D3: 2(1); D2: 4(3); D1: 5(4); M2: 8(1); M1: 5(1); B4: 7(0); Total: 43(14) [China: 5, Korea: 3, India: 2, Thailand:1, US: 1, UK: 1, Austria:1]





Octopus Growth

(*m*=60, *n*=6, 1600 K)

ACCVD Directly on Surfaces (Dip-Coat)



ACCVD Apparatus





Y. Murakami, S. Chiashi, Y. Miyauchi, M. Hu, M. Ogura, T. Okubo, S. Maruyama, Chem. Phys. Lett. 385 (2004) 298

Control of Diameter



Growth of VA-SWNTs from Ethanol and Acetonitrile



Raman of VA-SWNTs from Ethanol and Acetonitrile



Chirality Distribution







NEXAFS shows Aligned N2 molecules



C. Kramberger, T. Thurakitseree, H. Koh, Y. Izumi, T. Kinoshita, E. Einarsson, S. Maruyama, submitted (2012).

NEXAFS shows Aligned N2 molecules





Multi-Step Growth





Summary (C) (b) (a) 5%aceto 6 Intensity (arb. units) 5 4 EtOH (6,6) (7,7) Horizontally aligned SWNTs 5%aceto 1 on R-Plane Crystal Quartz **50 ս**m 2 µm 100 150 200 250 300 350 1300 1400 1500 1600 Raman shift (cm⁻¹) Raman shift (cm⁻¹) N2 inside VA-SWNT with D < 1 nm(a) (b) 2.0 Small SWNT gate electrode (top) G **PVA** diameter adhesion **PVA layer (middle)** 15 µm Maiko **Octopus Growth** Absorbance (scaled) 1. 0. S D **PVA** SWNT S/D electrodes and (d) .5 nm SWNT channel (bottom) SWNT channel (C) 1.4 nm DA DIL 0.5 600 1800 2400 3000 1200 SWNT 5 mm Wavelength (nm) 10 µm electrode **Diameter Control of VA-SWNT** Transparent flexible all CNT FET